

Description

The AR0504P4 is an ultra low capacitance TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The AR0504P4 complies with the IEC 61000-4-2 (ESD) with ±25kV air and ±20kV contact discharge. It is assembled into a 6-pin DFN2020-6 lead-free package. The leads are finished with NiPdAu. Each device will protect up to four high-speed lines. The combination of small size, low capacitance, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

Features

- Ultra low capacitance: 0.3pF typical (I/O to I/O)
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Up to 4 lines and one power line protects
- · Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±25kV
 - Contact discharge: ±20kV IEC61000-4-5 (Lightning) 5A (8/20µs)
- RoHS Compliant

Mechanical Characteristics

- Package: DFN2020-6
- Case Material: "Green" Molding CompoundTerminal Connections: See Diagram Below
- · Marking Information: See Below

Applications

- USB 2.0 and USB OTG
- Multi Media Card Interfaces
- SD Card Interfaces
- MDDI Ports
- SIM Ports

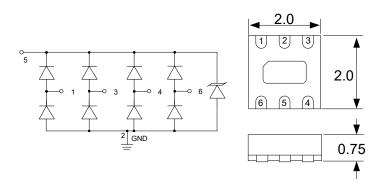
Marking Information



54P = Device Marking Code Dot denotes Pin1

Ordering Information

Dimensions and Pin Configuration



Part NumberPackagingReel SizeAR0504P43000/Tape & Reel7 inch

Circuit Diagram

Pin Schematic



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

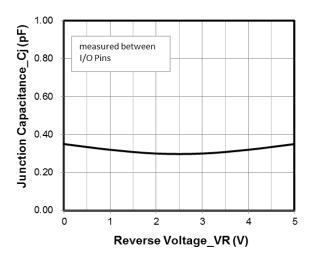
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	75	W
Peak Pulse Current (8/20µs)	IPP	5	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±25 ±20	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

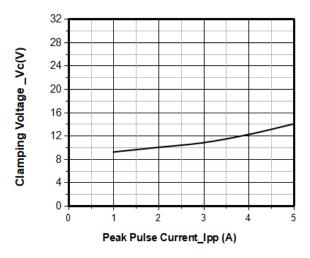
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	Any I/O to ground
Breakdown Voltage	VBR	6			V	IT = 1mA, any I/O to ground
Reverse Leakage Current	I _R			0.5	μA	VRWM = 5V, any I/O to ground
Clamping Voltage	Vc			10	V	IPP = 1A (8 x 20µs pulse), any I/O pin to ground
Clamping Voltage	Vc			15	V	IPP = 5A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	Cl			0.5	pF	VR = 0V, f = 1MHz, between I/O pins
Junction Capacitance	Сл			0.8	pF	VR = 0V, f = 1MHz, any I/O pin to ground



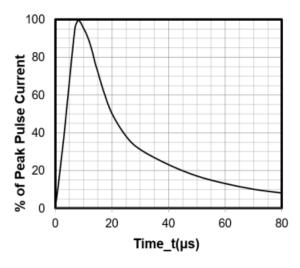
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



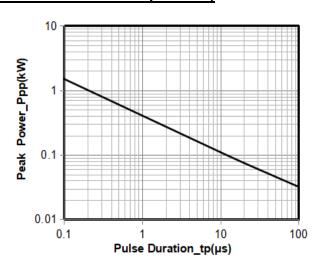
Junction Capacitance vs. Reverse Voltage



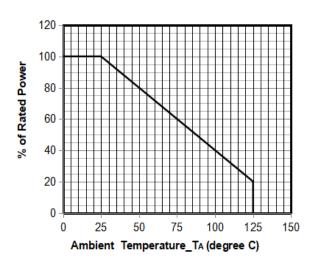
Clamping Voltage vs. Peak Pulse Current



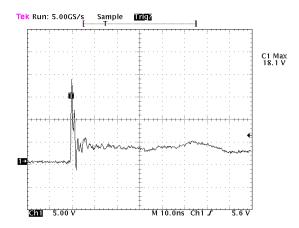
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Power Derating Curve



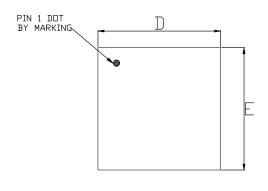
Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

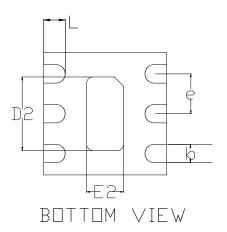
8 kV Contact per IEC61000-4-2



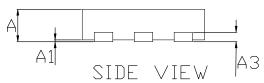
DFN2020-6 Package Outline Drawing



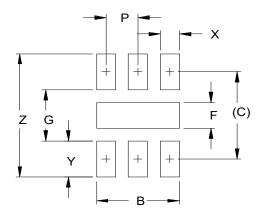




COMMON DIMENSIONS(MM)				
PKG.	W:very very THIN			
REF.	MIN.	N□M.	MAX	
Α	0.70	0.75	0.80	
A1	0.00	_	0,05	
A3	0.20 REF.			
D	1.95	2.00	2.05	
E	1.95	2.00	2.05	
D2	1.05	1.20	1.30	
E5	0.45	0.60	0.70	
b	0.25	0.30	0.35	
L	0.25	0,35	0.45	
ρ		0.65 RSC		



Suggested Land Pattern



DIMENSIONS				
DIM	INCHES	MILLIMETERS		
В	0.065	1.65		
С	0.070	1.95		
Р	0.026	0.65		
F	0.034	0.86		
G	0.049	1.25		
Х	0.014	0.35		
Υ	0.026	0.65		
Ζ	0.100	2.55		

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